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Vishay Semiconductors

## Ultralow V<sub>F</sub> Ultrafast Rectifier, 6 A FRED Pt®

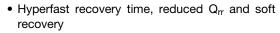




DPAK	(TO-252	ΔΔ

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 6 A						
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.26 V					
t <sub>rr</sub> (typ.)	18 ns					
T <sub>J</sub> max.	175 °C					
Package	DPAK (TO-252AA)					
Circuit configuration	Single					

#### **FEATURES**





RoHS

HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- Low forward voltage drop
- Low forward voltage are
- Low leakage current
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 144 °C	6				
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	70	Α			
Peak repetitive forward current	I <sub>FM</sub>	T <sub>C</sub> = 144 °C, f = 20 kHz, d = 50 %	12				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	.,		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 6 A	-	1.60	2.1	V		
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C	-	1.26	1.7			
Devenue le alcomo economist		$V_R = V_R$ rated	-	-	50			
Reverse leakage current	IR	$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	-	250	μA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	3.5	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 100$	) A/μs, V <sub>R</sub> = 30 V	-	18	25	
Dovorno ropovony timo		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	22	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 6 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 390 V	-	27	-	ns
		T <sub>J</sub> = 125 °C		-	37	-	
Dook recovery current	1	T <sub>J</sub> = 25 °C		-	4.1	-	Α
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	5.3	-	^
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	57	-	200
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	103	-	nC

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		ı	1	3	°C/W		
Approximate weight				0.3		g		
Approximate weight				0.01		oz.		
Marking device		Case style DPAK (TO-252AA)	6EWH06FNH					

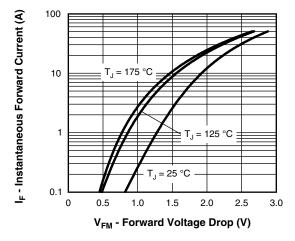


Fig. 1 - Typical Forward Voltage Drop Characteristics

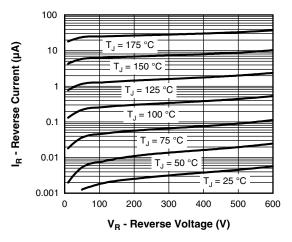


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

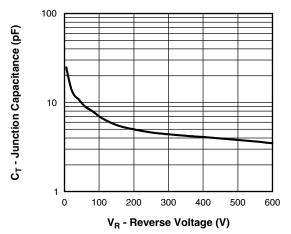


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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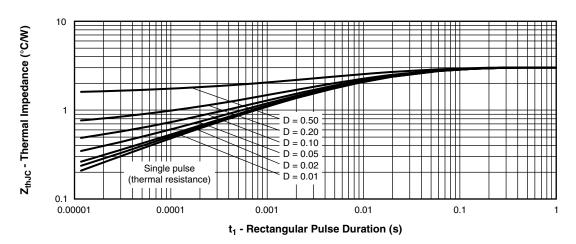


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

40

35

35

25

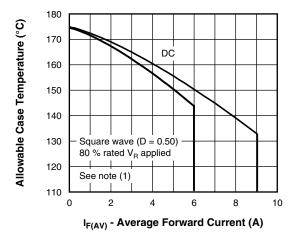
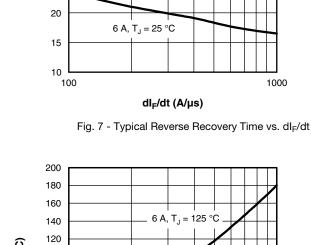


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



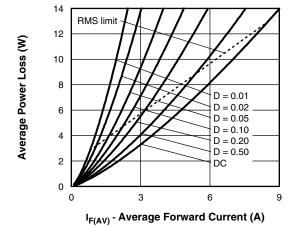
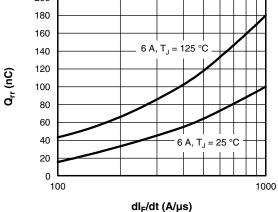


Fig. 6 - Forward Power Loss Characteristics



6 A, T<sub>.1</sub> = 125 °C

1000

Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

Formula used:  $T_C = T_J$  - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss =  $I_{F(AV)}$  x V<sub>FM</sub> at ( $I_{F(AV)}$ /D) (see fig. 6);  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$ 

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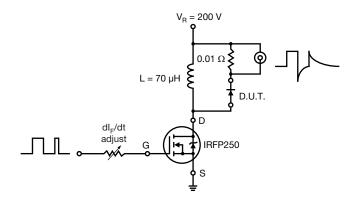
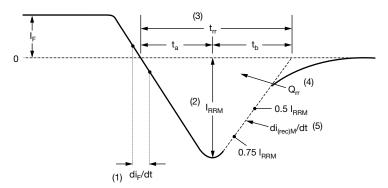


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

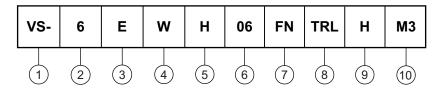
Fig. 10 - Reverse Recovery Waveform and Definitions



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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (6 = 6 A)

Circuit configuration:

E = single diode

Package identifier:

W = D-PAK

**5** - H = hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - FN = TO-252AA

8 - None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - H = AEC-Q101 qualified

|10| - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

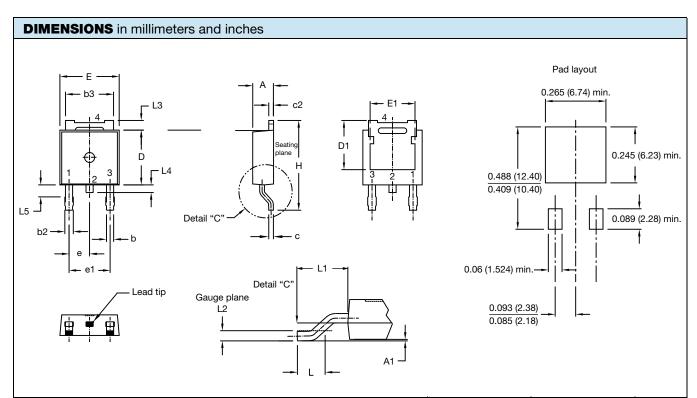
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6EWH06FNHM3	75	3000	Antistatic plastic tube				
VS-6EWH06FNTRHM3	2000	2000	13" diameter reel				
VS-6EWH06FNTRRHM3	3000	3000	13" diameter reel				
VS-6EWH06FNTRLHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95519					
Part marking information	www.vishay.com/doc?95518					
Packaging information	www.vishay.com/doc?95033					



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# **DPAK (TO-252AA)**



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	ı	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2

#### **Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (5) Outline conforms to JEDEC® outline TO-252AA



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